



浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO.,LTD.

产品规格书

Specification of products

产品名称：可控硅模块

产品型号：SKKH132A/16E-T07

浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO., LTD.

地址：浙江省 丽水市 莲都区

电话：(0578) 3012571 3615078

传真：(0578) 3611180

邮编：323000

E-mail: smrshiling01@163.com

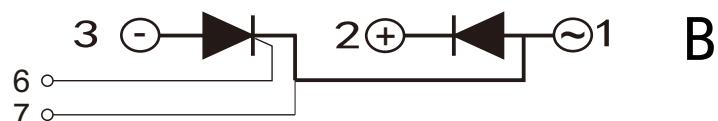
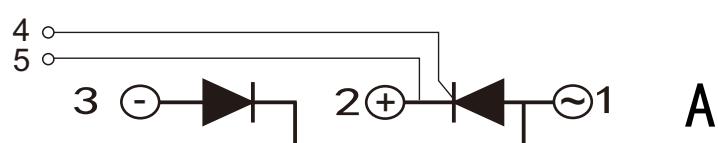
[Http://www.smrshiling.com](http://www.smrshiling.com)

拟制	审核	核准
林益龙	曹剑龙	宗瑞

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_J (°C)	VALUE			UNIT
				Min	Type	Max	
$I_{T(AV)}$ $I_{F(AV)}$	Mean on-state current	180° half sine wave 50Hz Single side cooled, $T_c=85^\circ C$	125			132	A
$I_{T(RMS)}$	RMS on-state current	Single side cooled, $T_c=85^\circ C$	125			207	A
V_{DRM} V_{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	$V_{DRM} \& V_{RRM}$ tp=10ms $V_{DsM} \& V_{RsM} = V_{DRM} \& V_{RRM} + 200V$ respectively	125		1600	1800	V
I_{DRM} I_{RRM}	Repetitive peak current	at V_{DRM} at V_{RRM}	125			20	mA
I_{TSM}	Surge on-state current	10ms half sine wave	125			3.80	KA
I^2t	I^2T for fusing coordination	$V_R=60\%V_{RRM}$				73.6 A^2s*10^3	
V_{TO}	Threshold voltage		125			0.8	V
r_T	On-state slop resistance					2.12	$m\Omega$
V_{TM}	Peak on-state voltage	$I_{TM}=396A$	125			1.40	V
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=67\%V_{DRM}$	125			1000	V/ μs
di/dt	Critical rate of rise of on-state current	From 67% V_{DRM} to 405A, Gate source 1.5A $t_r \leq 0.5 \mu s$ Repetitive	125			200	A/ μs
I_{GT}	Gate trigger current		25	30		150	mA
V_{GT}	Gate trigger voltage	$V_A=12V, I_A=1A$		0.8		2.0	V
I_H	Holding current			20		100	mA
V_{GD}	Non-trigger gate voltage	At 67% V_{DRM}	125			0.2	V
$R_{th(j-c)}$	Thermal resistance Junction to heatsink	At 180° sine Single side cooled				0.200	$^\circ C /W$
V_{iso}	Isolation voltage	50Hz, RM. S, t=1min, I_{iso} : 1mA (MAX)		2500			V
F_m	Thermal connection torque (M6)				5.0		N.m
	Mounting torque (M6)				5.0		N.m
T_{stg}	Stored temperature			-40		150	$^\circ C$
W_t	Weight				220		g
Outline							

OUTLINE DRAWING & CIRCUIT DIAGRAM

SKKH:



Rating and Characteristic

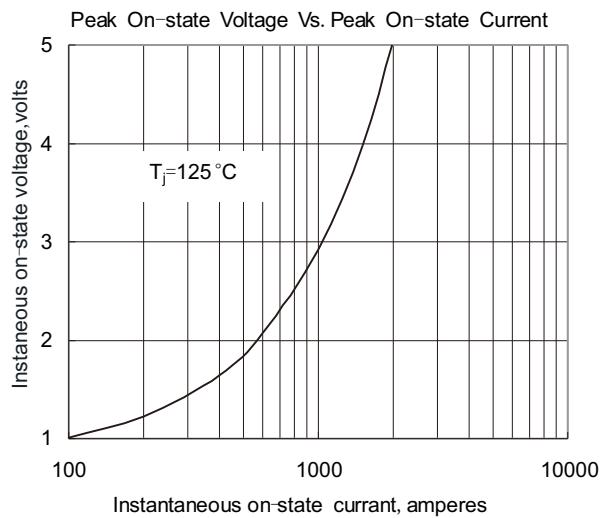


Fig.1

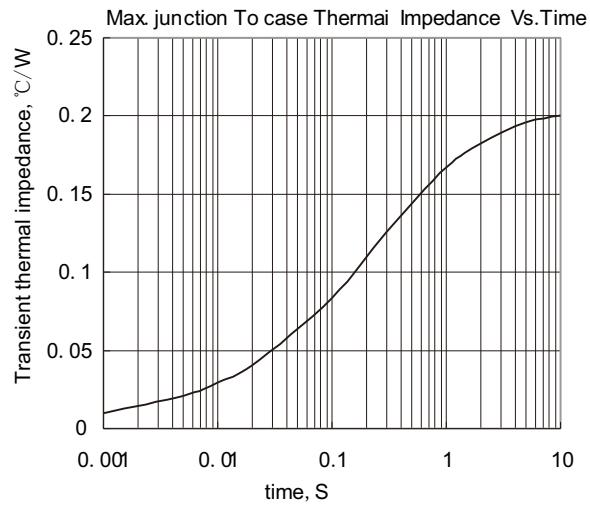


Fig.2

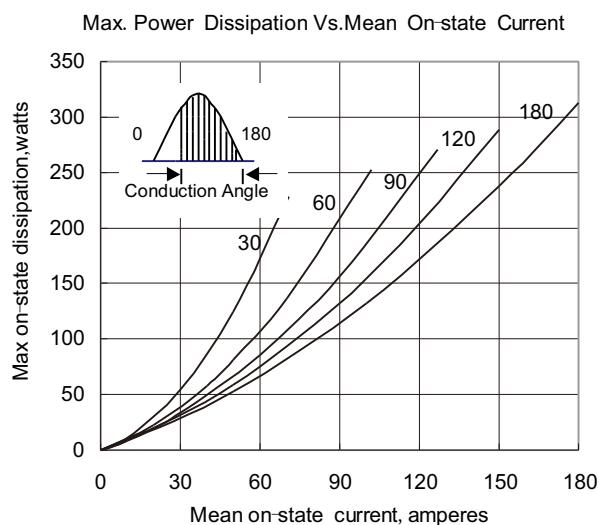


Fig.3

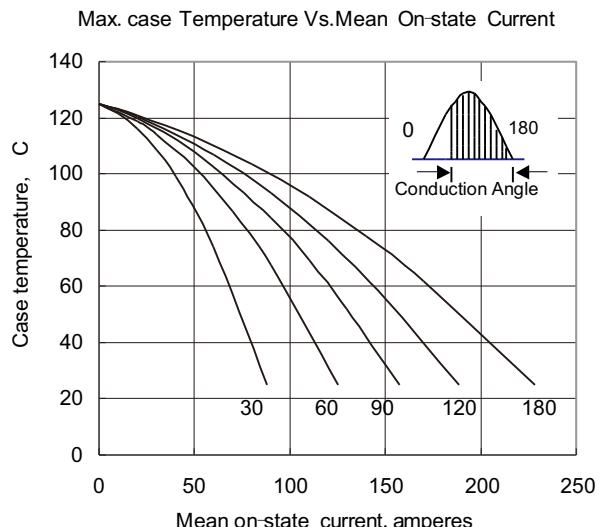


Fig.4

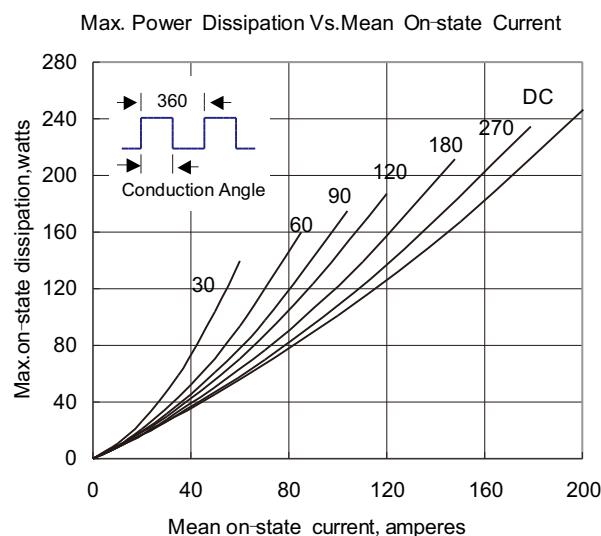


Fig.5

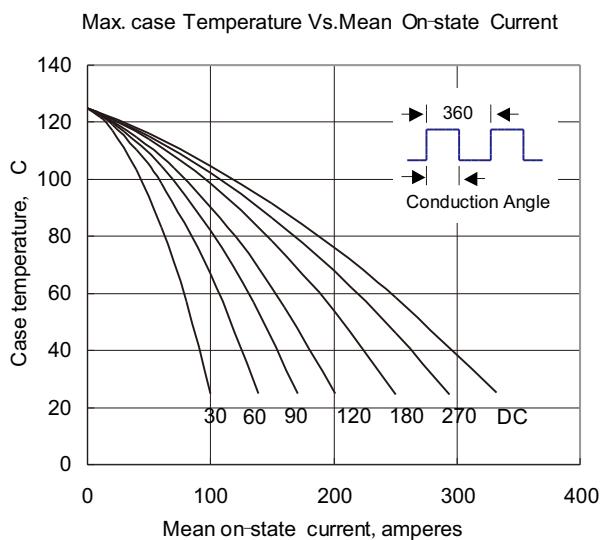


Fig.6

Rating and Characteristic

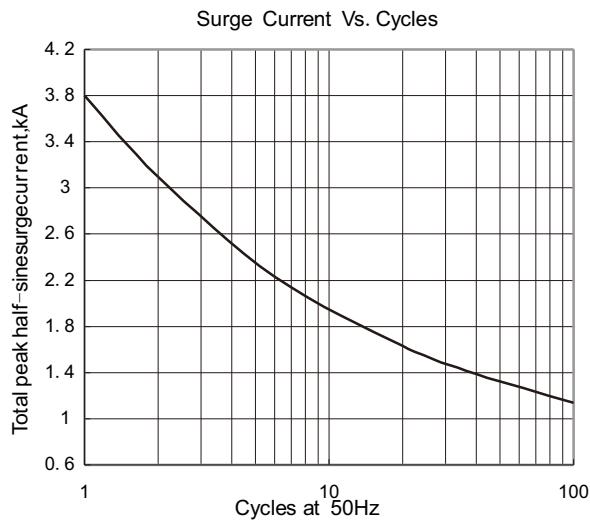


Fig. 7

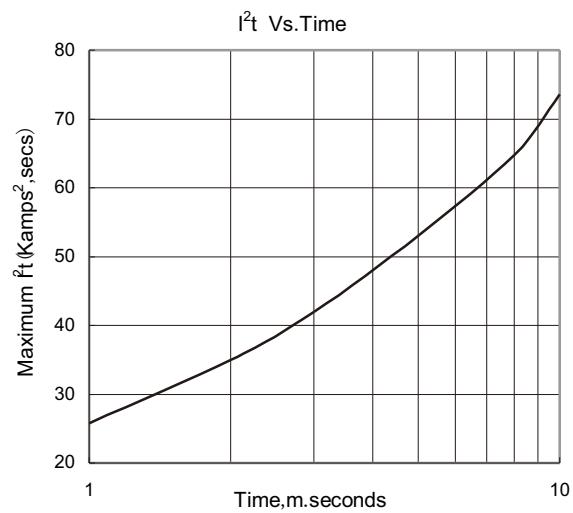


Fig. 8

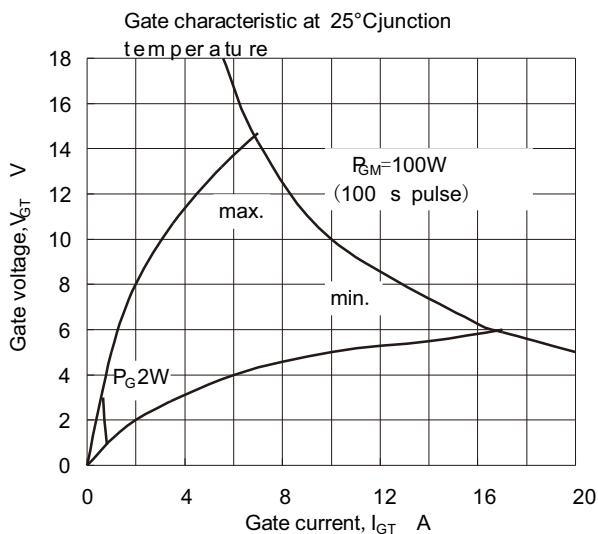


Fig. 9

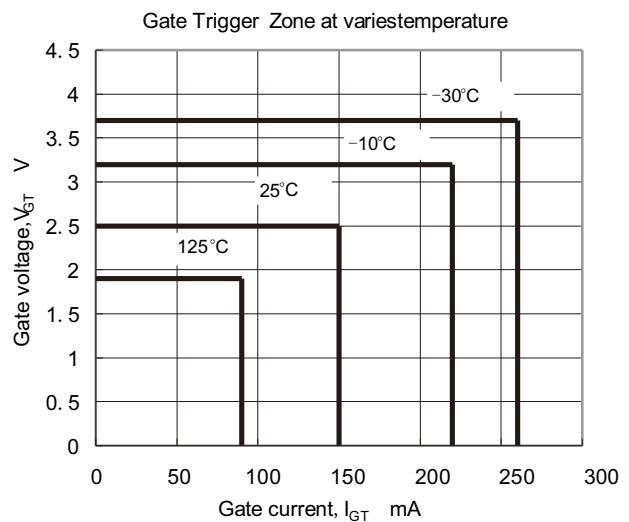


Fig. 10

Outside Dimension

